NE592

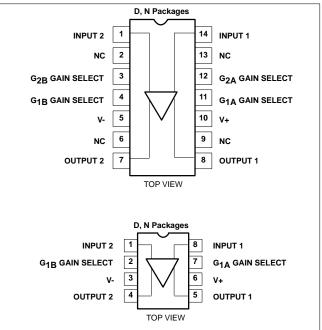
DESCRIPTION

The NE592 is a monolithic, two-stage, differential output, wideband video amplifier. It offers fixed gains of 100 and 400 without external components and adjustable gains from 400 to 0 with one external resistor. The input stage has been designed so that with the addition of a few external reactive elements between the gain select terminals, the circuit can function as a high-pass, low-pass, or band-pass filter. This feature makes the circuit ideal for use as a video or pulse amplifier in communications, magnetic memories, display, video recorder systems, and floppy disk head amplifiers. Now available in an 8-pin version with fixed gain of 400 without external components and adjustable gain from 400 to 0 with one external resistor.

FEATURES

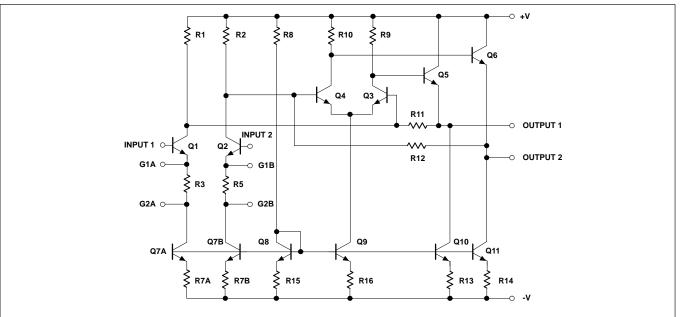
- 120MHz unity gain bandwidth
- Adjustable gains from 0 to 400
- Adjustable pass band
- No frequency compensation required
- Wave shaping with minimal external components
- MIL-STD processing available

PIN CONFIGURATIONS



APPLICATIONS

- Floppy disk head amplifier
- Video amplifier
- Pulse amplifier in communications
- Magnetic memory
- Video recorder systems



BLOCK DIAGRAM

NE592

ORDERING INFORMATION

DESCRIPTION	TEMPERATURE RANGE	ORDER CODE	DWG #
14-Pin Plastic Dual In-Line Package (DIP)	0 to +70°C	NE592N14	0405B
14-Pin Small Outline (SO) package	0 to +70°C	NE592D14	0175D
8-Pin Plastic Dual In-Line Package (DIP)	0 to +70°C	NE592N8	0404B
8-Pin Small Outline (SO) package	0 to +70°C	NE592D8	0174C

NOTES:

N8, N14, D8 and D14 package parts also available in "High" gain version by adding "H" before package designation, i.e., NE592HDB

ABSOLUTE MAXIMUM RATINGS

 $T_A=+25^{\circ}C$, unless otherwise specified.

SYMBOL	PARAMETER	RATING	UNIT
V _{CC}	Supply voltage	±8	V
V _{IN}	Differential input voltage	±5	V
V _{CM}	Common-mode input voltage	±6	V
I _{OUT}	Output current	10	mA
T _A	Operating ambient temperature range	0 to +70	°C
T _{STG}	Storage temperature range	-65 to +150	°C
P _{D MAX}	Maximum power dissipation,		
	T _A =25°C (still air)¹		
	D-14 package	0.98	W
	D-8 package	0.79	W
	N-14 package	1.44	W
	N-8 package	1.17	W

NOTES:

1. Derate above 25°C at the following rates: D-14 package at 7.8mW/°C D-8 package at 6.3mW/°C N-14 package at 11.5mW/°C

N-8 package at 9.3mW/°C

NE592

DC ELECTRICAL CHARACTERISTICS

T_A=+25°C V_{SS}=±6V, V_{CM}=0, unless otherwise specified. Recommended operating supply voltages V_S=±6.0V. All specifications apply to both standard and high gain parts unless noted differently.

SYMBOL	PARAMETER	TEST CONDITIONS	NE592			
			Min	Тур	Max	
A _{VOL}	Differential voltage gain,					
	standard part					
	Gain 1 ¹	R _L =2kΩ, V _{OUT} =3V _{P-P}	250	400	600	V/V
	Gain 2 ^{2, 4}		80	100	120	V/V
R _{IN}	Input resistance					
	Gain 1 ¹			4.0		kΩ
	Gain 2 ^{2, 4}		10	30		kΩ
C _{IN}	Input capacitance ²	Gain 2 ⁴		2.0		pF
I _{OS}	Input offset current			0.4	5.0	μA
I _{BIAS}	Input bias current			9.0	30	μA
V _{NOISE}	Input noise voltage	BW 1kHz to 10MHz		12		μV_{RMS}
V _{IN}	Input voltage range		±1.0			V
CMRR	Common-mode rejection ratio					
	Gain 2 ⁴	V _{CM} ±1V, f<100kHz	60	86		dB
	Gain 2 ⁴	V _{CM} ±1V, f=5MHz		60		dB
PSRR	Supply voltage rejection ratio					
	Gain 2 ⁴	ΔV_{S} =±0.5V	50	70		dB
V _{OS}	Output offset voltage					
	Gain 1	R _L =∞			1.5	V
	Gain 2 ⁴	R _L =∞			1.5	V
	Gain 3 ³	R _L =∞		0.35	0.75	V
V _{CM}	Output common-mode voltage	R _L =∞	2.4	2.9	3.4	V
V _{OUT}	Output voltage swing	$R_L=2k\Omega$	3.0	4.0		V
	differential					
R _{OUT}	Output resistance			20		Ω
I _{CC}	Power supply current	R _L =∞		18	24	mA

NOTES:
1. Gain select Pins G_{1A} and G_{1B} connected together.
2. Gain select Pins G_{2A} and G_{2B} connected together.
3. All gain select pins open.
4. Applies to 14-pin version only.

NE592

DC ELECTRICAL CHARACTERISTICS

DC Electrical Characteristics V_{SS}= \pm 6V, V_{CM}=0, 0°C \leq T_A \leq 70°C, unless otherwise specified. Recommended operating supply voltages V_S= \pm 6.0V. All specifications apply to both standard and high gain parts unless noted differently.

SYMBOL	PARAMETER	TEST CONDITIONS	NE592			
			Min	Тур	Max	UNIT
A _{VOL}	Differential voltage gain,					
	standard part					
	Gain 1 ¹	R _L =2kΩ, V _{OUT} =3V _{P-P}	250		600	V/V
	Gain 2 ^{2, 4}		80		120	V/V
R _{IN}	Input resistance					
	Gain 2 ^{2, 4}		8.0			kΩ
I _{OS}	Input offset current				6.0	μA
I _{BIAS}	Input bias current				40	μA
V _{IN}	Input voltage range		±1.0			V
CMRR	Common-mode rejection ratio					
	Gain 2 ⁴	V _{CM} ±1V, f<100kHz	50			dB
PSRR	Supply voltage rejection ratio					
	Gain 2 ⁴	$\Delta V_{S}=\pm 0.5 V$	50			dB
V _{OS}	Output offset voltage Gain 1 Gain 2 ⁴ Gain 3 ³	R _L =∞			1.5 1.5 1.0	V
V _{OUT}	Output voltage swing differential	$R_L=2k\Omega$	2.8			V
I _{CC}	Power supply current	R _L =∞			27	mA

NOTES:

1. Gain select Pins G_{1A} and G_{1B} connected together. 2. Gain select Pins G_{2A} and G_{2B} connected together. 3. All gain select pins open. 4. Applies to 14-pin versions only.

AC ELECTRICAL CHARACTERISTICS

T_A=+25°C V_{SS}=±6V, V_{CM}=0, unless otherwise specified. Recommended operating supply voltages V_S=±6.0V. All specifications apply to both standard and high gain parts unless noted differently.

SYMBOL	PARAMETER	TEST CONDITIONS	NE/SA592			UNIT
			Min	Тур	Max	
BW	Bandwidth Gain 1 ¹ Gain 2 ^{2, 4}			40 90		MHz MHz
t _R	Rise time Gain 1 ¹ Gain 2 ^{2, 4}	V _{OUT} =1V _{P-P}		10.5 4.5	12	ns ns
t _{PD}	Propagation delay Gain 1 ¹ Gain 2 ^{2, 4}	V _{OUT} =1V _{P-P}		7.5 6.0	10	ns ns

NOTES:

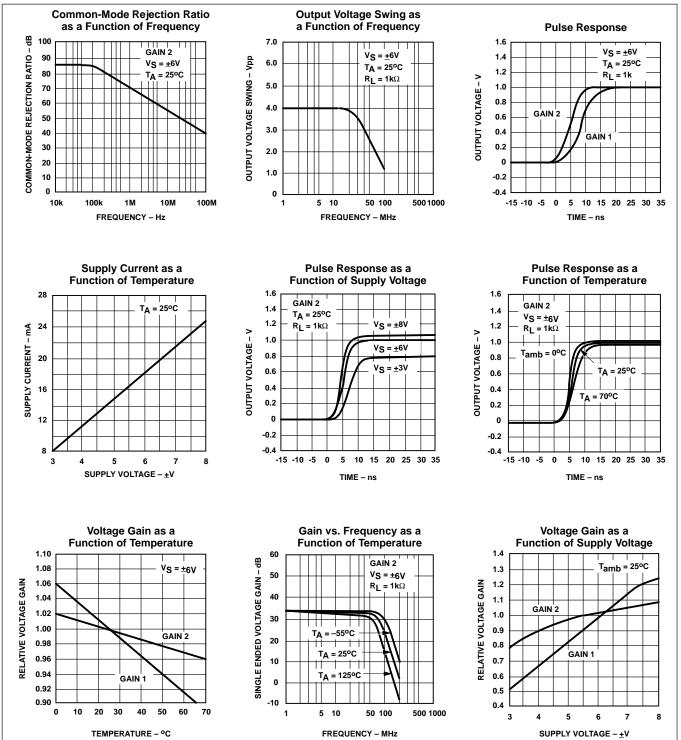
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4. Applies to 14-pin versions only.

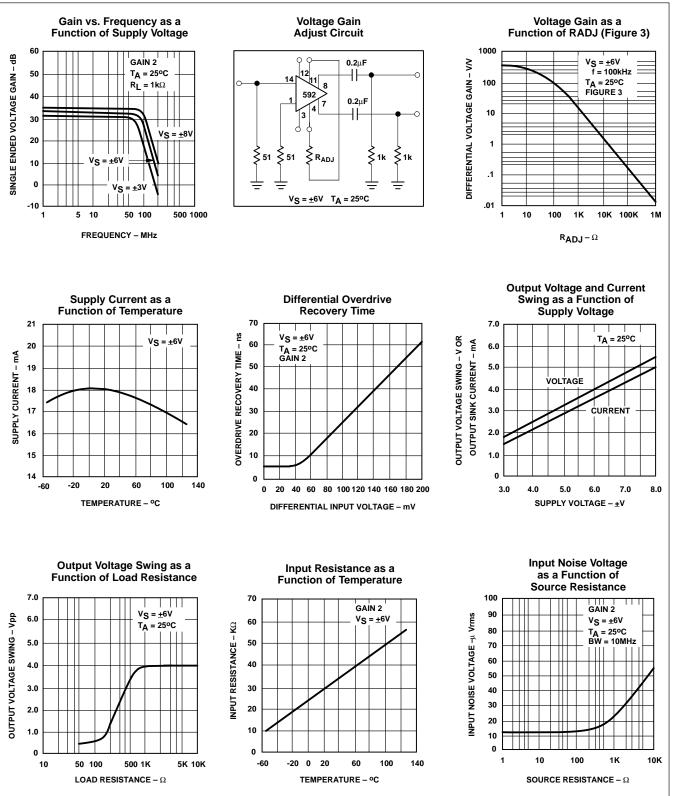
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TYPICAL PERFORMANCE CHARACTERISTICS

Philips Semiconductors RF Communications Products

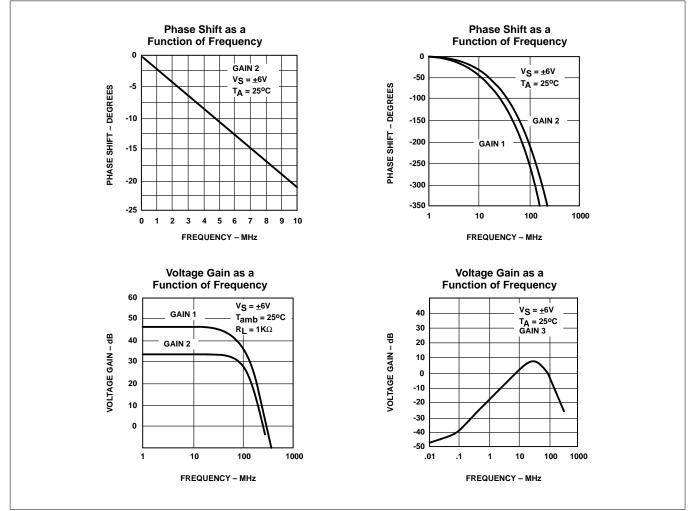


TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

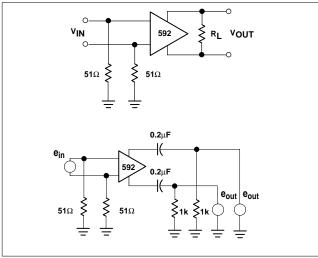


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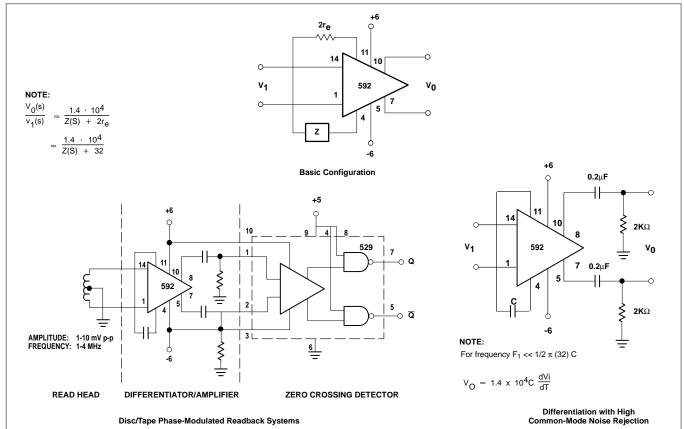


TEST CIRCUITS $T_A = 25^{\circ}C$, unless otherwise specified.

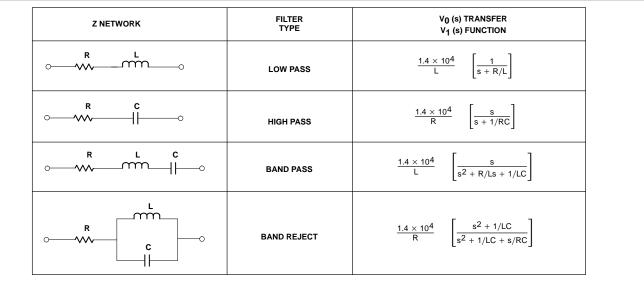


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TYPICAL APPLICATIONS



FILTER NETWORKS



NOTES:

In the networks above, the R value used is assumed to include 2re, or approximately 32Ω. $S = j\omega$ $\omega = 2\pi f$